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August 2016

FAN48617 Fixed-Output Synchronous TinyBoost® Regulator

Features

Input Voltage Range: 2.7 V to 4.5 V

Output Voltage: 5.0 V

1000 mA Max. Load Capability

PWM Only

Up to 97% Efficient

Forced Pass-Through Operation via EN Pin

Internal Synchronous Rectification

True Load Disconnect

Short-Circuit Protection

External Components: 2016 (Metric) 1 µH Inductor, 0402 Case Size Input / Output Capacitors

Applications

- Class-D Audio Amplifier
- Boost for Low-Voltage Li-Ion Batteries
- Smart Phones, Tablets, Portable Devices
- **RF** Applications
- **NFC Applications**

Description

The FAN48617 is a low-power PWM only boost regulator designed to provide a minimum voltage-regulated rail from a standard single-cell Li-lon battery and advanced battery chemistries. Even below the minimum system battery voltage, the device maintains the output voltage regulation for an output load current of 1000 mA. The combination of built-in power transistors, synchronous rectification, and low supply current suit the FAN48617 for battery-powered applications.

The FAN48617 is available in a 9-bump, 0.4 mm pitch, (1.215 x 1.215 mm) Wafer-Level Chip-Scale Package (WLCSP).

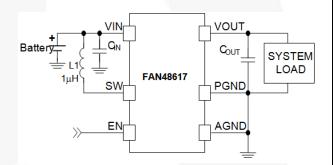


Figure 1. Typical Application

Ordering Information

Part Number	V _{OUT}	Operating Temperature	Package	Packing	Device Marking
FAN48617UC50X	5.0 V	-40°C to 85°C	9-Bump, 0.4 mm Pitch, WLCSP Package	Tape and Reel	K2

Block Diagram

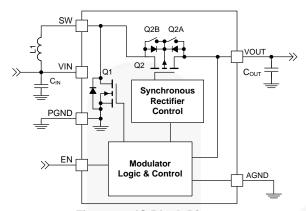


Figure 2. IC Block Diagram

Recommended Components Table 1.

Component	Description	Vendor	Parameter	Тур.	Unit
L1	20%, 3.9 A, 2016, 1.0 mm	DFE201610E-1R0M	Inductance	1	μΗ
LI	Height TOKO		DCR (Series R)	48	mΩ
C _{IN}	20%, 6.3 V, X5R, 0402 (1005)	C1005X5R0J106M050BC TDK	Capacitance	10	
C _{OUT} 1 ⁽¹⁾	20%, 6.3 V, X5R, 0402 (1005)	C1005X5R0J106M050BC TDK	Capacitance	2 x 10	μF
C _{OUT} 2 ⁽²⁾	20%, 6.3 V, X5R, 0402 (1005)	C1005X5R0J106M050BC TDK	Capacitance	3 x 10	7

- For applications with $I_{OUT} < 500$ mA use $C_{OUT}\,1.$ For applications with 500 mA $\leq I_{OUT} < 1000$ mA use $C_{OUT}\,2.$

Pin Configuration

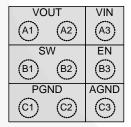


Figure 3. Top View

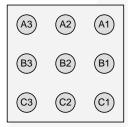


Figure 4. Bottom View

Pin Definitions

Pin#	Name	Description			
A1, A2	VOUT	Output Voltage. This pin is the output voltage terminal; connect directly to C _{OUT} .			
А3	VIN	nput Voltage. Connect to Li-lon battery input power source and C _{IN} .			
B1, B2	SW	Switching Node. Connect to inductor.			
В3	EN	Enable . When this pin is HIGH, the circuit is enabled. After part is engaged, pin forces part into Forced-Pass-Through Mode when EN pin is pulled LOW.			
C1, C2 PGND Power Ground. This is the power return for the IC. Cout capacitor should be returned with the shortest path possible to these pins.		Power Ground . This is the power return for the IC. C _{OUT} capacitor should be returned with the shortest path possible to these pins.			
C3	AGND	Analog Ground . This is the signal ground reference for the IC. All voltage levels are measured with respect to this pin – connect to PGND at a single point.			

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parar	Min.	Max.	Unit	
V _{IN}	Voltage on VIN Pin			6.0	V
Vout	Voltage on VOUT Pin			6.0	V
Vsw	SW Node	DC	-0.3	6.0	V
VSW	Svv Node	Transient: 10 ns, 3 MHz	-1.0	8.0	
V _{CC}	Voltage on Other Pins		-0.3	6.0 ⁽³⁾	V
ESD	Flacticatatic Discharge Protection Level	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	2	kV	
ESD	Electrostatic Discharge Protection Level	Charged Device Model per JESD22- C101		.0	KV
TJ	Junction Temperature		-40	+150	°C
T _{STG}	Storage Temperature		-65	+150	°C
T_L	Lead Soldering Temperature, 10 Second	s		+260	°C

Note:

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter		Max.	Unit
V_{IN}	Supply Voltage	2.7	4.5	V
lout	Maximum Output Current	1000		mA
T _A	Ambient Temperature	-40	+85	°C
T_J	Junction Temperature	-40	+125	°C

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p boards with vias in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature, $T_{J(max)}$, at a given ambient temperature, T_A .

Symbol	Parameter	Typical	Unit
Θ_{JA}	Junction-to-Ambient Thermal Resistance	50	°C/W

^{3.} Lesser of 6.0 V or V_{IN} + 0.3 V.

Electrical Specifications

Recommended operating conditions, unless otherwise noted, circuit per Figure 1, V_{OUT} = 5.0 V. Typical, minimum and maximum values are given at V_{IN} = 3.6 V, T_A = 25°C, -40°C, and +85°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Power Su	pply		1	ı		
		I _{OUT} = 0 mA, EN = 1.8 V, No Switching		95		
IQ	V _{IN} Quiescent Current	Forced Pass-Through EN = 0 V, V _{OUT} = V _{IN}		3.5		μА
V _{UVLO}	Under-Voltage Lockout	V _{IN} Rising		2.20		V
V _{UVLO_HYS}	Under-Voltage Lockout Hysteresis			150		mV
Inputs						
V _{IH}	Enable HIGH Voltage		1.05			V
V _{IL}	Enable LOW Voltage				0.4	V
Outputs			•			
V_{REG}	Output Voltage Accuracy DC(4)	$2.7 \text{ V} \le \text{V}_{\text{IN}} \le 4.5 \text{ V}$	-2		+2	%
Timing						
f_{SW}	Switching Frequency	I _{OUT} = 300 mA	1.8	2.3	2.8	MHz
t _{SS} ⁽⁵⁾	EN HIGH to 95% of Regulation	I _{OUT} = 150 mA		425		μS
t _{RST} ⁽⁵⁾	FAULT Restart Timer			20		ms
Power S	Stage					
R _{DS(ON)N}	N-Channel Boost Switch R _{DS(ON)}			63		mΩ
R _{DS(ON)P}	P-Channel Sync. Rectifier R _{DS(ON)}			52		mΩ

Notes:

- 4. DC I_{LOAD} from 0 to 1000 mA. V_{OUT} measured from mid-point of output voltage ripple. Effective capacitance of $C_{OUT} \ge 6.3 \ \mu F$.
- 5. Guaranteed by design and characterization; not tested in production.

Typical Performance Characteristics

Unless otherwise specified; $V_{IN}=3.6$ V, $V_{OUT}=5.0$ V, $T_A=25^{\circ}$ C, and circuit according to Figure 1. Components: $C_{IN}=10~\mu\text{F}$, $C_{OUT}=3~x~10~\mu\text{F}$ (0402, X5R, 6.3 V, C1005X5R0J106M050BC), L1 = 1 μH (2016, 48 m Ω , DFE201610E-1R0M).

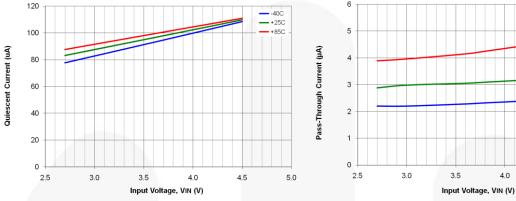


Figure 5. Quiescent Current (No Switching) vs. Input Voltage and Temperature

Input Voltage, VIN (V)

Figure 6. Pass-Through Current vs. Input Voltage and Temperature

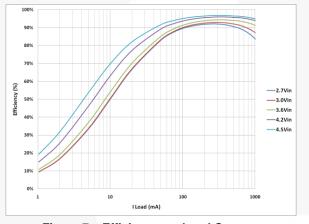


Figure 7. Efficiency vs. Load Current and Input Voltage

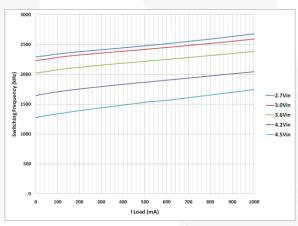


Figure 8. Switching Frequency vs. Load Current and Input Voltage

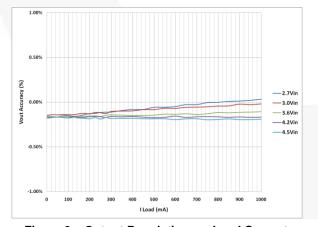


Figure 9. Output Regulation vs. Load Current and Input Voltage

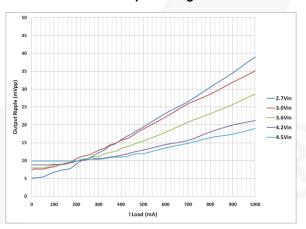
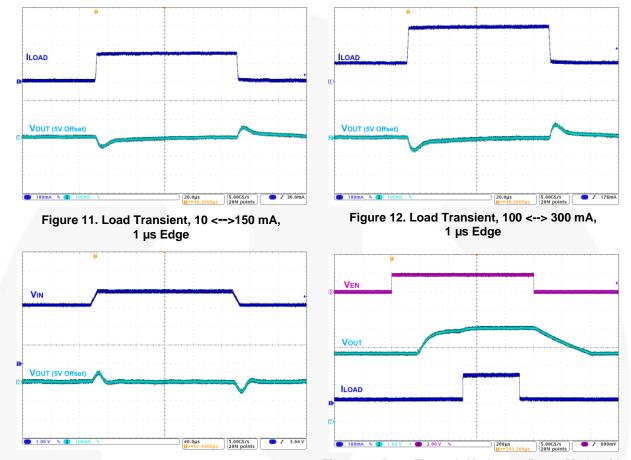


Figure 10. Output Ripple vs. Load Current and Input Voltage

Typical Performance Characteristics

Unless otherwise specified; $V_{IN}=3.6$ V, $V_{OUT}=5.0$ V, $T_A=25^{\circ}$ C, and circuit and components according to Figure 1. Components: $C_{IN}=10~\mu\text{F}$, $C_{OUT}=3~x~10~\mu\text{F}$ (0402, X5R, 6.3 V, C1005X5R0J106M050BC), L1 = 1 μH (2016, 48 m Ω , DFE201610E-1R0M).



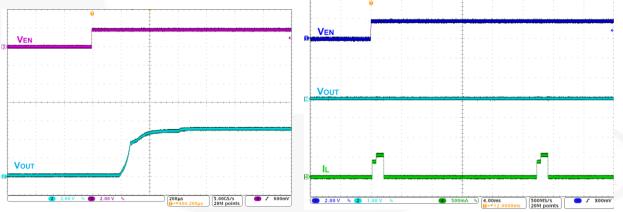


Figure 15. Startup, 150 mA Load

Figure 16. Fault Restart

Circuit Description

FAN48617 is a synchronous PWM Only boost regulator. The regulator's Pass-Through Mode automatically activates when V_{IN} is above the boost regulator's set point.

Table 2. Operating Modes

Mode	Description	Invoked When:
LIN	Linear Startup	$V_{IN} > V_{OUT}$
SS	Boost Soft-Start	V _{IN} < V _{OUT} < V _{OUT(TARGET)}
BST	Boost Operating Mode	V _{OUT} = V _{OUT(TARGET)}
PT	Pass-Through Mode	V _{IN} > V _{OUT(TARGET)} or when EN is pulled LOW after initial startup

Boost Mode Regulation

The FAN48617 uses a current-mode modulator to achieve excellent transient response.

Table 3. Boost Startup Sequence

Start Mode	Entry	Exit	End Mode	Timeout (µs)
LIN1	V _{IN} > V _{UVLO} ,	V _{OUT} > V _{IN} - 300 mV	SS	
	EN=1	Timeout	LIN2	512
LIN2	LIN1 Exit	V _{OUT} > V _{IN} - 300 mV	SS	
		Timeout	FAULT	1024
SS	LIN1 or	Vout=Vout(target	BST	
33	LIN2 Exit	Overload Timeout	FAULT	64

LIN Mode

When EN is HIGH and $V_{\text{IN}} > V_{\text{UVLO}}$, the regulator first attempts to bring V_{OUT} within 300 mV of V_{IN} by using the internal fixed-current source from VIN (Q2). The current is limited to the LIN1 set point.

If V_{OUT} reaches V_{IN} -300 mV during LIN1 Mode, the SS Mode is initiated. Otherwise, LIN1 times out after 512 μ s and LIN2 Mode is entered.

In LIN2 Mode, the current source is incremented. If V_{OUT} fails to reach $V_{\text{IN}}\text{-}300$ mV after 1024 μs , a fault condition is declared and the device waits 20 ms to attempt an automatic restart.

Soft-Start (SS) Mode

Upon the successful completion of LIN Mode ($V_{OUT} \ge V_{IN} = 300 \text{ mV}$), the regulator begins switching with boost pulses current limited to 50% of nominal level.

During SS Mode, if V_{OUT} fails to reach regulation during the SS ramp sequence for more than 64 μs , a fault is declared. If large C_{OUT} is used, the reference is

automatically stepped slower to avoid excessive input current draw.

Boost (BST) Mode

This is a normal operating mode of the regulator.

Pass-Through (PT) Mode

The device allows the user to force the device in Forced Pass-Through Mode through the EN pin. If the EN pin is pulled HIGH, the device starts operating in Boost Mode. Once the EN pin is pulled LOW, the device is forced into Pass-Through Mode. To disable the device, the input supply voltage must be removed. The device cannot startup in Forced Pass-Through Mode (see Figure 17). During startup, keep the EN pulled HIGH for at least 350 µs before pulling it LOW in order to make sure that the device enters Pass-Through Mode realiably

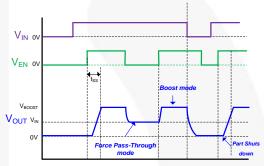


Figure 17. Pass-Through Profile

Current Limit Protection

The FAN48617 has valley current limit protection in case of overload situations. The valley current limit will prevent high current from causing damage to the IC and the inductor. The current limit is halved during soft-start.

When starting into a fault condition, the input current will be limited by LIN1 and LIN2 current threshold.

Fault State

The regulator enters Fault State under any of the following conditions:

- V_{OUT} fails to achieve the voltage required to advance from LIN Mode to SS Mode.
- V_{OUT} fails to achieve the voltage required to advance from SS Mode to BST Mode.
- Boost current limit triggers for 2 ms during BST Mode.
- V_{IN} V_{OUT} > 300 mV; this fault can occur only after successful completion of the soft-start sequence.
- V_{IN} < V_{UVLO}.

Once a fault is triggered, the regulator stops switching and presents a high-impedance path between VIN and VOUT. After waiting 20 ms, an automatic restart is attempted.

Over-Temperature

The regulator shuts down if the die temperature exceeds 150°C and restarts when the IC cools by ~20°C.

Application Information

Output Capacitance (Cout)

The effective capacitance ($C_{\text{EFF}}^{(6)}$) of small, high-value ceramic capacitors decreases as their bias voltage increases, as illustrated in the graph below:

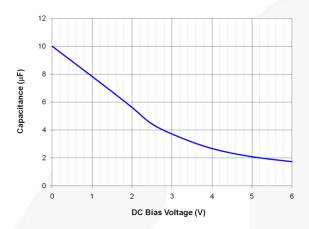


Figure 18. C_{EFF} for 10 μF, 0402, X5R, 6.3 V-Rated Capacitor (TDK C1005X5R0J106M050BC)

FAN48617 is guaranteed for stable operation with the minimum value of C_{EFF} ($C_{\text{EFF}(MIN)}$) outlined in Table 4.

Table 4. Minimum C_{EFF} Required for Stability

Ope	C _{EFF(MIN)}		
V _{OUT} (V)	V _{IN} (V)	I _{LOAD} (mA)	(μ F)
5.0	2.7 to 4.5	0 to 500	4.2
5.0	2.7 to 4.5	0 to 1000	6.3

Note:

Layout Recommendations

The layout recommendations below highlight various top-copper pours by using different colors.

To minimize spikes at VOUT, C_{OUT} must be placed as close as possible to PGND and VOUT, as shown in Figure 19.

For best thermal performance, maximize the pour area for all planes other than SW. The ground pour, especially, should fill all available PCB surface area and be tied to internal layers with a cluster of thermal vias.

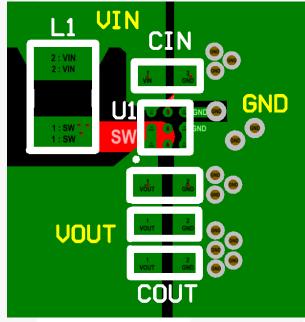


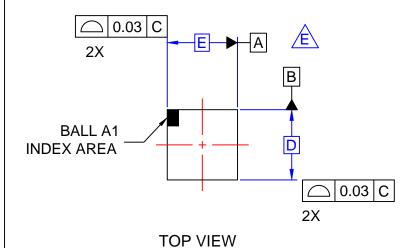
Figure 19. Layout Recommendation

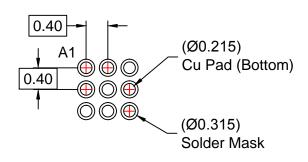
The table below pertains to MOD drawing on the following page.

Product-Specific Package Dimensions

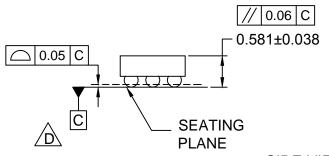
Product	D	E	х	Υ
FAN48617UC50X	1.215 ±0.030 mm	1.215 ±0.030 mm	0.2075 mm	0.2075 mm

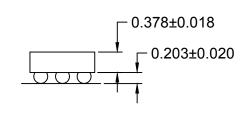
C_{EFF} varies by manufacturer, capacitor material, and case size.





RECOMMENDED LAND PATTERN (NSMD PAD TYPE)



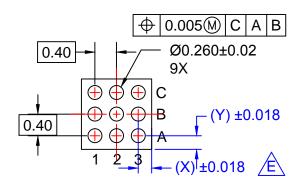


SIDE VIEWS

NOTES

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 2009.
- D. DATUM C IS DEFINED BY THE

 SPHERICAL CROWNS OF THE BALLS.
- E. FOR DIMENSIONS D,E,X, AND Y SEE PRODUCT DATASHEET.
- F. DRAWING FILNAME: MKT-UC009Ak rev3



BOTTOM VIEW

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